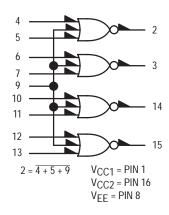
Quad 2-Input NOR Gate With Strobe

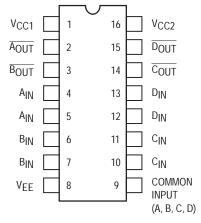
The MC10H100 is a quad NOR gate. Each gate has 3 inputs, two of which are independent and one of which is tied common to all four gates.

- Propagation Delay, 1.0 ns Typical
- 25 mW Typ/Gate (No Load)
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K-Compatible

LOGIC DIAGRAM



DIP PIN ASSIGNMENT



Pin assignment is for Dual–in–Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).



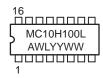
ON Semiconductor

http://onsemi.com

MARKING DIAGRAMS



CDIP-16 L SUFFIX CASE 620





PDIP-16 P SUFFIX CASE 648





PLCC-20 FN SUFFIX CASE 775



A = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week

ORDERING INFORMATION

| Device | Package | Shipping | |
|------------|---------|---------------|--|
| MC10H100L | CDIP-16 | 25 Units/Rail | |
| MC10H100P | PDIP-16 | 25 Units/Rail | |
| MC10H100FN | PLCC-20 | 46 Units/Rail | |

MAXIMUM RATINGS

| Symbol | Characteristic | Rating | Unit | |
|------------------|--|----------------------------|------|--|
| VEE | Power Supply (V _{CC} = 0) | -8.0 to 0 | Vdc | |
| VI | V _I Input Voltage (V _{CC} = 0) | | | |
| l _{out} | Output Current – Continuous – Surge | 50 100 | mA | |
| TA | Operating Temperature Range | 0 to +75 | °C | |
| T _{stg} | Storage Temperature Range – Plastic – Ceramic | -55 to +150 -55 to +165 | °C | |

ELECTRICAL CHARACTERISTICS ($V_{EE} = -5.2 \text{ V} \pm 5\%$) (See Note 1.)

| | | 0 ° | | 25° | | 75° | | |
|-------------------|---|------------|------------|--------|------------|--------|------------|------|
| Symbol | Characteristic | Min | Max | Min | Max | Min | Max | Unit |
| ΙE | Power Supply Current | _ | 29 | _ | 26 | - | 29 | mA |
| l _{in} H | Input Current High Pin 9 All Other Inputs | - - | 900 500 | - - | 560 310 | - - | 560 310 | μΑ |
| l _{inL} | Input Current Low | 0.5 | _ | 0.5 | _ | 0.3 | _ | μΑ |
| Voн | High Output Voltage | -1.02 | -0.84 | -0.98 | -0.81 | -0.92 | -0.735 | Vdc |
| VOL | Low Output Voltage | -1.95 | -1.63 | -1.95 | -1.63 | -1.95 | -1.60 | Vdc |
| V_{IH} | High Input Voltage | -1.17 | -0.84 | -1.13 | -0.81 | -1.07 | -0.735 | Vdc |
| V _{IL} | Low Input Voltage | -1.95 | -1.48 | -1.95 | -1.48 | -1.95 | -1.45 | Vdc |

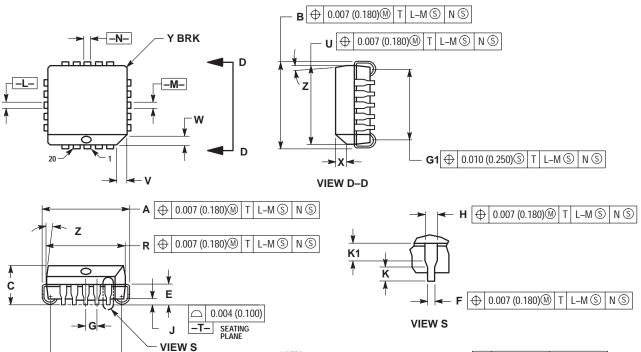
AC PARAMETERS

| tı | od | Propagation Delay Pin 9 Only Exclude Pin 9 | 0.65 0.4 | 1.6 1.3 | 0.7 0.45 | 1.7 1.35 | 0.7 0.5 | 1.8 1.5 | ns |
|----|----------------|--|-------------|------------|-------------|-------------|------------|------------|----|
| | t _r | Rise Time | 0.5 | 2.0 | 0.5 | 2.1 | 0.5 | 2.2 | ns |
| | t _f | Fall Time | 0.5 | 2.0 | 0.5 | 2.1 | 0.5 | 2.2 | ns |

^{1.} Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 Ifpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts.

PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX** PLASTIC PLCC PACKAGE CASE 775-02 **ISSUE C**



G

⊕ 0.010 (0.250)③ T L-M ⑤ N ⑤

- OILES:

 1. DATUMS -L-, -M-, AND -N- DETERMINED

 WHERE TOP OF LEAD SHOULDER EXITS PLASTIC
 BODY AT MOLD PARTING LINE.
- BUDY AT MULD PARTING LINE.

 2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

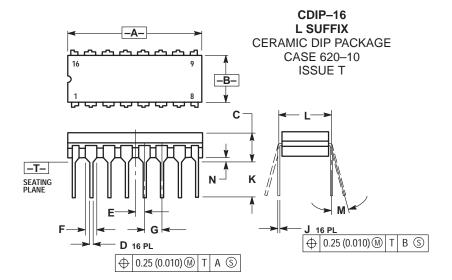
 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250)
- PER SIDE.

 4. DIMENSIONING AND TOLERANCING PER ANSI

- 4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 5. CONTROLLING DIMENSION: INCH.
 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, CATE BURDES AND INTERIOR AN GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

 7. DIMENSION H DOES NOT INCLUDE DAMBAR
- DIMENSION H DUES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635)

| | INCHES | | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.385 | 0.395 | 9.78 | 10.03 |
| В | 0.385 | 0.395 | 9.78 | 10.03 |
| С | 0.165 | 0.180 | 4.20 | 4.57 |
| Ε | 0.090 | 0.110 | 2.29 | 2.79 |
| F | 0.013 | 0.019 | 0.33 | 0.48 |
| G | 0.050 | BSC | 1.27 | BSC |
| Н | 0.026 | 0.032 | 0.66 | 0.81 |
| J | 0.020 | | 0.51 | |
| K | 0.025 | | 0.64 | |
| R | 0.350 | 0.356 | 8.89 | 9.04 |
| U | 0.350 | 0.356 | 8.89 | 9.04 |
| V | 0.042 | 0.048 | 1.07 | 1.21 |
| W | 0.042 | 0.048 | 1.07 | 1.21 |
| Χ | 0.042 | 0.056 | 1.07 | 1.42 |
| Υ | | 0.020 | | 0.50 |
| Z | 2° | 10° | 2 ° | 10 ° |
| G1 | 0.310 | 0.330 | 7.88 | 8.38 |
| K1 | 0.040 | | 1.02 | |
| | | | | |

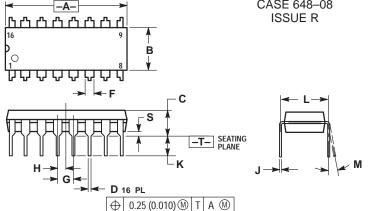


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEAD WHEN
- FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC

| | INC | HES | MILLIN | IETERS | |
|-----------|-------|-----------|--------|--------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.750 | 0.785 | 19.05 | 19.93 | |
| В | 0.240 | 0.295 | 6.10 | 7.49 | |
| С | | 0.200 | | 5.08 | |
| D | 0.015 | 0.020 | 0.39 | 0.50 | |
| Ε | 0.050 | BSC | 1.27 | BSC | |
| F | 0.055 | 0.065 | 1.40 | 1.65 | |
| G | 0.100 | BSC | 2.54 | BSC | |
| Н | 0.008 | 0.015 | 0.21 | 0.38 | |
| K 0.125 0 | | 0.170 | 3.18 | 4.31 | |
| L | | 0.300 BSC | | BSC | |
| M | M 0° | | 0 ° | 15° | |
| N | 0.020 | 0.040 | 0.51 | 1.01 | |





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL

| | INC | HES | MILLIMETERS | | |
|-----|-----------|-------|-------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.740 | 0.770 | 18.80 | 19.55 | |
| В | 0.250 | 0.270 | 6.35 | 6.85 | |
| С | 0.145 | 0.175 | 3.69 | 4.44 | |
| D | 0.015 | 0.021 | 0.39 | 0.53 | |
| F | 0.040 | 0.70 | 1.02 | 1.77 | |
| G | 0.100 BSC | | 2.54 BSC | | |
| Н | 0.050 | BSC | 1.27 BSC | | |
| J | 0.008 | 0.015 | 0.21 | 0.38 | |
| K | 0.110 | 0.130 | 2.80 | 3.30 | |
| L | 0.295 | 0.305 | 7.50 | 7.74 | |
| M | 0° | 10° | 0 ° | 10 ° | |
| S | 0.020 | 0.040 | 0.51 | 1.01 | |
| | | | | | |

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